

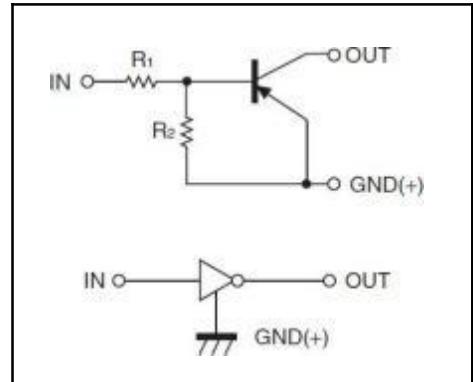
Digital Transistors (Built-in Resistors)

• Equivalent Circuit

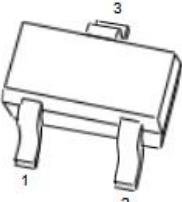
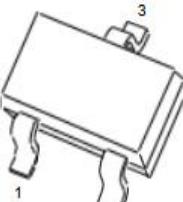
DIGITAL TRANSISTOR (PNP)

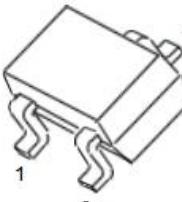
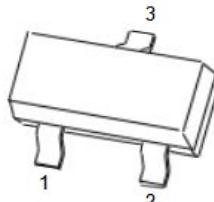
FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



PIN CONNECTIONS and MARKING

DTA143ZE		SOT-523	DTA143ZUA		SOT-323
		1. IN 2. GND 3. OUT			1. IN 2. GND 3. OUT

DTA143ZKA		SOT-23-3L	DTA143ZCA		SOT-23
		1. IN 2. GND 3. OUT			1. IN 2. GND 3. OUT

ORDERING INFORMATION

Part Number	MARKING ⁽¹⁾	Package	Packing Method	Pack Quantity
DTA143ZE	E13	SOT-523	Reel	3000pcs/Reel
DTA143ZUA	E13	SOT-323	Reel	3000pcs/Reel
DTA143ZKA	E13	SOT-23-3L	Reel	3000pcs/Reel
DTA143ZCA	E13	SOT-23	Reel	3000pcs/Reel

MAXIMUM RATINGS(T_a=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTA143Z□)						Unit
			E	UA	KA	CA		
V _{cc}	Supply Voltage	-50						V
V _{IN}	Input Voltage	-30~+5						V
I _o	Output Current	-100						mA
P _D	Power Dissipation	150	200	200	200			mW
T _j	Junction Temperature	150						°C
T _{stg}	Storage Temperature	-55~+150						°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{cc} =-5V,I _o =-100μA	-0.5			V
	V _{I(on)}	V _O =-0.3V,I _o =-5mA			-1.3	V
Output voltage	V _{O(on)}	I _o /I _i =-5mA/-0.25mA			-0.3	V
Input current	I _i	V _i =-5V			-1.8	mA
Output current	I _{O(off)}	V _{cc} =-50V,V _i =0			-0.5	μA
DC current gain	G _i	V _O =-5V,I _o =-10mA	80			
Input resistance	R _i		3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁		8	10	12	
Transition frequency	f _T	V _O =-10V,I _o =-5mA,f=100MHz		250		MHz

Typical Characteristics

